

SEMICONDUCTOR®

LM336-5.0/LM336B-5.0 Programmable Shunt Regulator

Features

- Low temperature coefficient
- Adjustable 4V to 6V
- Wide operating range current of 10mA to 400mA
- Three lead transistor package (TO-92)
- 0.6 ohm dynamic impedance
- ±1.0% initial tolerance available
- Guaranteed temperature stability
- Easily trimmed for minimum temperature drift
- Fast turn on

Description

The LM336-5.0 / LM336B-5.0 integrated circuits are precision 5.0V shunt regulators. The monolithic IC voltage reference operates as a low temperature coefficient 5.0V zener with 0.60hm dynamic impedance. A third terminal on the LM336-5.0/LM336B-5.0 allow the reference voltage and temperature coefficient to be trimmed easily. The LM336-5.0/LM336B-5.0 are useful as a precision 5.0V low voltage references which makes it convenient to obtain a stable reference from low voltage supplies. Further, since the LM336-5.0/LM336B-5.0 operate as shunt regulators, they can be used as either a positive or negative voltage reference.



Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Reverse Current	IR	15	mA
Forward current	lF	10	mA
Operating Temperature Range LM336/LM336B-0.5	TOPR	0 ~ +70	°C
Storage Temperature Range	TSTG	-60 ~ +150	٥C

Electrical Characteristics

 $(0^{\circ}C \le T_A \le +70^{\circ}C$ unless otherwise specified)

Parameter Symbol Conditions		nhol Conditions		LM336-5.0		LM336B-5.0			Unit
		Min.	Тур.	Max.	Min.	Тур.	Max.	Unit	
Reverse Breakdown Voltage	VR	$T_A = 25^{\circ}C$, $I_R = 1mA$	4.8	5.0	5.2	4.9	5.0	5.1	V
Reverse Breakdown Change with Current	ΔVR/ΔIR	$\begin{array}{l} T_{A} = 25^{\circ}C \\ 600 \mu A \leq I_{R} \leq 10 mA \end{array}$	-	6	20	-	6	20	mV
Reverse Dynamic Impedance	ZD	TA = 25°C, IR = 1mA	-	0.6	2	-	0.6	2	Ω
Temperature Stability	STT	I _R = 1mA	-	4	12	-	4	12	mV
Reverse Breakdown Change with Current	$\Delta V_R / \Delta I_R$	$600\mu A \le I_R \le 10mA$	-	6	24	-	6	24	mV
Reverse Dynamic Impedance	ZD	I _R = 1mA	-	0.8	2.5	-	0.8	2.5	Ω
Long Term Stability In Reference Voltage	ST	I _R = 1mA	-	20	-	-	20	-	ppm/ Khr



Typical Perfomance Characteristics

Figure 1. Reverse Characteristics



Figure 3. Forward Characteristics



Figure 2. Temperature Drift



Figure 4. Reverse Voltage Change

Mechanical Dimensions

Package



TO-92

Ordering Information

Product Number	Package	Operating Temperature			
LM336Z5	TO 02	0~+70°C			
LM336BZ50	10-92				

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